AUTOMOTIVE GRADE

RoHS

COMPLIANT

HALOGEN

**FREE** 



### Vishay General Semiconductor

# High Current Density Surface-Mount Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.54 \text{ V}$  at  $I_F = 2.5 \text{ A}$ 



1 and / or 2 o 7, 8 3 and / or 4 o 5, 6

### **DESIGN SUPPORT TOOLS**

click logo to get started



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 5 A					
$V_{RRM}$	120 V					
I <sub>FSM</sub>	100 A					
$V_F$ at $I_F = 5$ A ( $T_A = 125$ °C)	0.62 V					
T <sub>J</sub> max.	175 °C					
Package	FlatPAK 5 x 6					
Circuit configuration	Separated cathode					

#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
- Automotive ordering code: base P/NHM3
   Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in low voltage high frequency DC/DC converters, freewheeling diodes, and polarity protection applications.

#### **MECHANICAL DATA**

Case: FlatPAK 5 x 6

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	V10KM120DU	UNIT			
Device marking code		V10M12D				
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	120	V			
Maximum DC forward current per diode	I <sub>F(AV)</sub> (1)	5	А			
	I <sub>F(AV)</sub> (2)	2.5	А			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	100	А			
Operating junction temperature range	T <sub>J</sub> <sup>(3)</sup>	-40 to +175	°C			
Storage temperature range	T <sub>STG</sub>	-55 to +175	°C			

#### Notes

- (1) With infinite heatsink
- (2) Free air, mounted on recommended pad area
- $^{(3)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$



# Vishay General Semiconductor

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.64	-	V
	I <sub>F</sub> = 5.0 A			0.81	0.89	
	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 125 °C		0.54	-	
	I <sub>F</sub> = 5.0 A			0.62	0.70	
Reverse current per diode	V <sub>R</sub> = 90 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	0.01	-	mA
	v <sub>R</sub> = 90 v	T <sub>A</sub> = 125 °C		0.8	-	
	V <sub>R</sub> = 120 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	0.35	
		T <sub>A</sub> = 125 °C		1.6	6	
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	450	-	pF

#### **Notes**

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TYP.	MAX.	UNIT		
Thermal resistance per diode	R <sub>0</sub> JA (1)(2)	100	-	°C/W		
	R <sub>0JM</sub> (3)	3.0	4.0			

#### Notes

- $^{(1)}$  The heat generated must be less than thermal conductivity from junction to ambient:  $dP_D/dT_J < 1/R_{\theta JA}$
- (2) Free air, mounted on recommended copper pad area; thermal resistance R<sub>0JA</sub> junction to ambient
- $^{(3)}$  Mounted on infinite heatsink; thermal resistance  $R_{\theta JM}$  junction-to-mount

ORDERING INFORMATION (Example)							
PREFERRED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE		P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE		DELIVERY MODE			
V10KM120DU-M3/H	0.10	Н	1500	7" diameter plastic tape and reel			
V10KM120DU-M3/I	0.10	1	6000	13" diameter plastic tape and reel			
V10KM120DUHM3/H (1)	0.10	Н	1500	7" diameter plastic tape and reel			
V10KM120DUHM3/I (1)	0.10	I	6000	13" diameter plastic tape and reel			

#### Note

(1) AEC-Q101 qualified



# Vishay General Semiconductor

### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

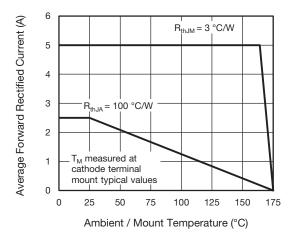


Fig. 1 - Maximum Forward Current Derating Curve

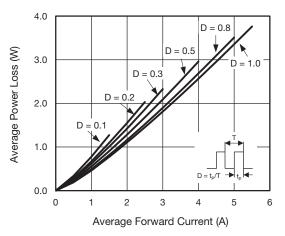


Fig. 2 - Forward Power Loss Characteristics

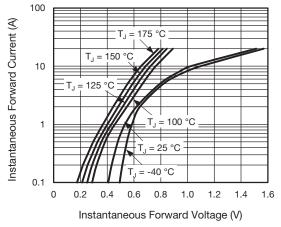


Fig. 3 - Typical Instantaneous Forward Characteristics

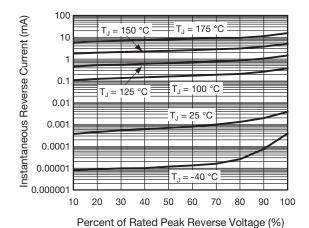


Fig. 4 - Typical Reverse Leakage Characteristics

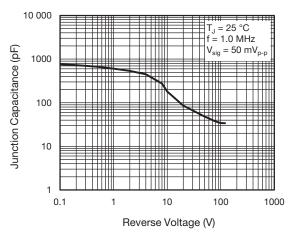


Fig. 5 - Typical Junction Capacitance

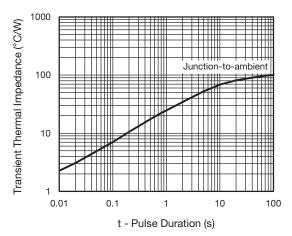
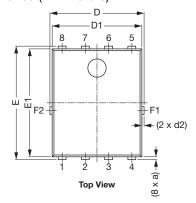


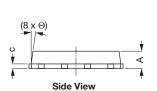
Fig. 6 - Typical Transient Thermal Impedance

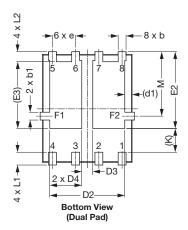


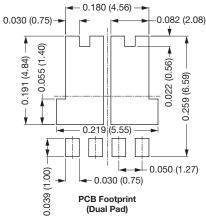
# Vishay General Semiconductor

### **DIMENSIONS** in inches (millimeters)









DIM.	INCHES			MILLIMETERS			
DIIVI.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	0.035	0.039	0.043	0.89	0.99	1.09	
(a)	-	0.006	-	-	0.15	-	
b	0.013	0.017	0.020	0.32	0.43	0.52	
b1	0.013	0.017	0.020	0.32	0.43	0.52	
С	0.008	-	0.014	0.20	-	0.35	
D	0.197	0.203	0.209	5.00	5.15	5.30	
D1	0.189	0.193	0.197	4.80	4.90	5.00	
D2	0.154	0.161	0.169	3.90	4.10	4.30	
D3	0.020	0.024	0.031	0.50	0.60	0.80	
D4	0.063	0.069	0.075	1.60	1.75	1.90	
(d1)	-	0.016	-	-	0.40	-	
(d2)	-	0.005	-	-	0.125	-	
E	0.238	0.244	0.250	6.05	6.20	6.35	
E1	0.228	0.232	0.236	5.80	5.90	6.00	
E2	0.157	0.165	0.173	4.00	4.20	4.40	
(E3)	-	0.144	Ū	-	3.65	I	
е		0.050 BSC			1.27 BSC		
(K)	0.039	-	Ū	1.00	-	Ū	
L1	0.019	-	0.043	0.48	-	1.10	
L2	0.012	-	0.031	0.30	-	0.80	
М	0.128	0.138	0.148	3.25	3.50	3.75	
Θ	0°	-	10°	0°	-	10°	

#### Notes

- Dimensioning and tolerancing per ASME Y14.5-2009
- Dimensions D1 and E1 do not include mold flash or gate burrs
- Dimension (XX) means reference only

Revision: 18-Jul-2018 4 Document Number: 87537



### **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below:

MA4E2039 D1FH3-5063 MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30 BAS16E6433HTMA1 BAT
54-02LRH E6327 NSR05F40QNXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T SK32A-LTP SK33A-TP
SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP
SK33B-TP SK35A-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF
ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA340-HF
ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573
NTE6081